
**Road vehicles — Component test methods
for electrical disturbances from
narrowband radiated electromagnetic
energy —**

**Part 3:
Transverse electromagnetic (TEM) cell**

*Véhicules routiers — Méthodes d'essai d'un équipement soumis à des
perturbations électriques par rayonnement d'énergie électromagnétique en
bande étroite —*

Partie 3: Cellule à mode électromagnétique transverse (TEM)



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Foreword

ISO (the International Organization for Standardization) is a worldwide federation of national standards bodies (ISO member bodies). The work of preparing International Standards is normally carried out through ISO technical committees. Each member body interested in a subject for which a technical committee has been established has the right to be represented on that committee. International organizations, governmental and non-governmental, in liaison with ISO, also take part in the work. ISO collaborates closely with the International Electrotechnical Commission (IEC) on all matters of electrotechnical standardization.

International Standards are drafted in accordance with the rules given in the ISO/IEC Directives, Part 3.

Draft International Standards adopted by the technical committees are circulated to the member bodies for voting. Publication as an International Standard requires approval by at least 75 % of the member bodies casting a vote.

Attention is drawn to the possibility that some of the elements of this part of ISO 11452 may be the subject of patent rights. ISO shall not be held responsible for identifying any or all such patent rights.

International Standard ISO 11452-3 was prepared by Technical Committee ISO/TC 22, *Road vehicles*, Subcommittee SC 3, *Electrical and electronic equipment*.

This second edition cancels and replaces the first edition (ISO 11452-3:1995), which has been technically revised.

ISO 11452 consists of the following parts, under the general title *Road vehicles — Component test methods for electrical disturbances from narrowband radiated electromagnetic energy*.

- *Part 1: General and definitions*
- *Part 2: Absorber-lined shielded enclosure*
- *Part 3: Transverse electromagnetic (TEM) cell*
- *Part 4: Bulk current injection (BCI)*
- *Part 5: Stripline*
- *Part 6: Parallel plate antenna*
- *Part 7: Direct radio frequency (RF) power injection*

Annexes A to D of this part of ISO 11452 are for information only.

Introduction

Immunity measurements of complete road vehicles are generally able to be carried out only by the vehicle manufacturer, owing to, for example, high costs of absorber-lined shielded enclosures, the desire to preserve the secrecy of prototypes or a large number of different vehicle models.

For research, development and quality control, a laboratory measuring method can be used by both vehicle manufacturers and equipment suppliers to test electronic components.

The TEM cell method has the major advantage of not radiating energy into the surrounding environment. The method can be used for testing either the immunity of a component with the field coupling to the wiring harness or the immunity of the component alone with minimum exposure to the wiring harness.

Road vehicles — Component test methods for electrical disturbances from narrowband radiated electromagnetic energy —

Part 3: Transverse electromagnetic (TEM) cell

1 Scope

This part of ISO 11452 specifies transverse electromagnetic (TEM) cell tests for determining the immunity of electronic components of passenger cars and commercial vehicles to electrical disturbances from narrowband radiated electromagnetic energy, regardless of the vehicle propulsion system (e.g. spark-ignition engine, diesel engine, electric motor).

The electromagnetic disturbances considered are limited to continuous narrowband electromagnetic fields.

2 Normative reference

The following normative document contains provisions which, through reference in this text, constitute provisions of this part of ISO 11452. For dated references, subsequent amendments to, or revisions of, any of these publications do not apply. However, parties to agreements based on this part of ISO 11452 are encouraged to investigate the possibility of applying the most recent edition of the normative document indicated below. For undated references, the latest edition of the normative document referred to applies. Members of ISO and IEC maintain registers of currently valid International Standards.

ISO 11452-1, *Road vehicles — Component test methods for electrical disturbances by narrowband radiated electromagnetic energy — Part 1: General and definitions.*

3 Terms and definitions

For the purposes of this part of ISO 11452, the terms and definitions given in ISO 11452-1 apply.

4 Test conditions

The upper frequency range limit of the TEM cell is a direct function of the TEM cell dimensions.

For testing automotive electronic systems, a 0,01 MHz to 200 MHz TEM cell should be used. See annex A for suggested cell dimensions.

The user shall specify the test severity level or levels over the frequency range. See annex D for suggested test severity levels.

Standard test conditions shall be those given in ISO 11452-1 for the following:

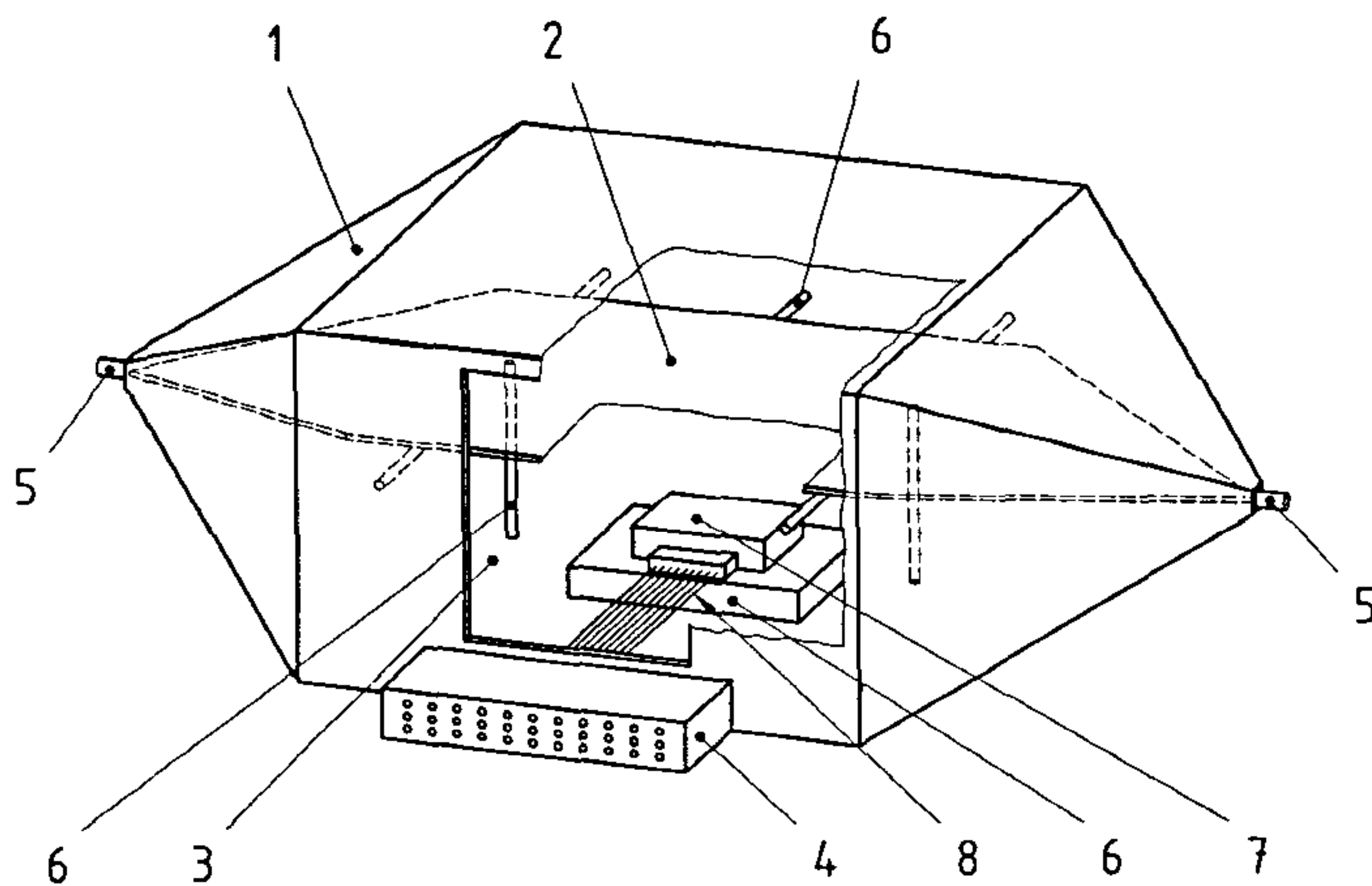
- test temperature;
- supply voltage;
- modulation;
- dwell time;
- frequency step sizes;
- definition of test severity levels;
- test-signal quality.

5 Test apparatus

5.1 TEM cell

The TEM cell used for this test is a rectangular coaxial line with a 50 Ω characteristic impedance (see Figure 1). The device under test is exposed to a uniform TEM field.

The TEM cell is a laboratory measurement system which can be used to generate test fields within 2 dB of the theoretical value if the device under test does not occupy an excessive portion of the test volume (see 5.3).



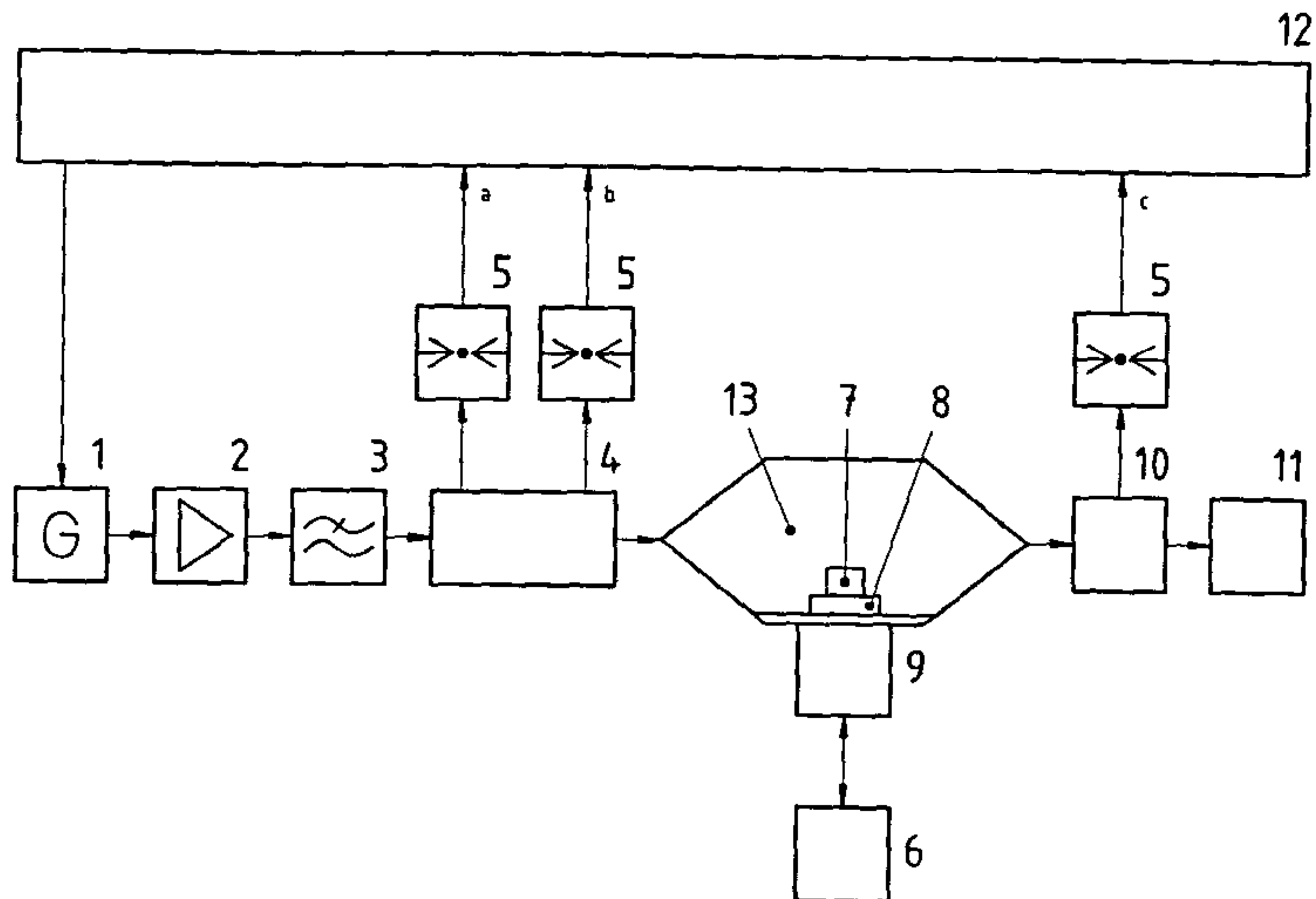
Key

- | | | | |
|---|----------------------------|---|---|
| 1 | Outer conductor (shield) | 5 | Coaxial connectors |
| 2 | Septum (inner conductor) | 6 | Dielectric support (relative permittivity $\epsilon_r \leq 1,4$) |
| 3 | Access door | 7 | Device under test |
| 4 | Connector panel (optional) | 8 | Input/output leads |

Figure 1 — TEM cell

5.2 Instrumentation

Figure 2 shows an example of a TEM cell test set-up. The TEM cell has high resonances in the region greater than the recommended upper frequency limit. A low pass filter with an attenuation of at least 60 dB at frequencies above 1,5 times the cut-off frequency of the TEM cell shall be installed (e.g. 200 MHz TEM cell: 60 dB for frequencies above 300 MHz).



Key

- 1 Signal generator
 - 2 Broadband amplifier
 - 3 Low pass filter
 - 4 Dual-directional coupler (30 dB decoupling ratio minimum)
 - 5 RF-power meter
 - 6 Peripheral
 - 7 Device under test
 - 8 Dielectric support
 - 9 Low pass filters/connector panel
 - 10 Coupler
 - 11 High power load (50 Ω)
 - 12 Controller
 - 13 TEM cell
- a $P_{\text{reflected}}$ (reflected power).
 b P_{forward} (forward power).
 c P_{output} (output power).

Figure 2 — Example TEM cell configuration

5.3 Test set-up

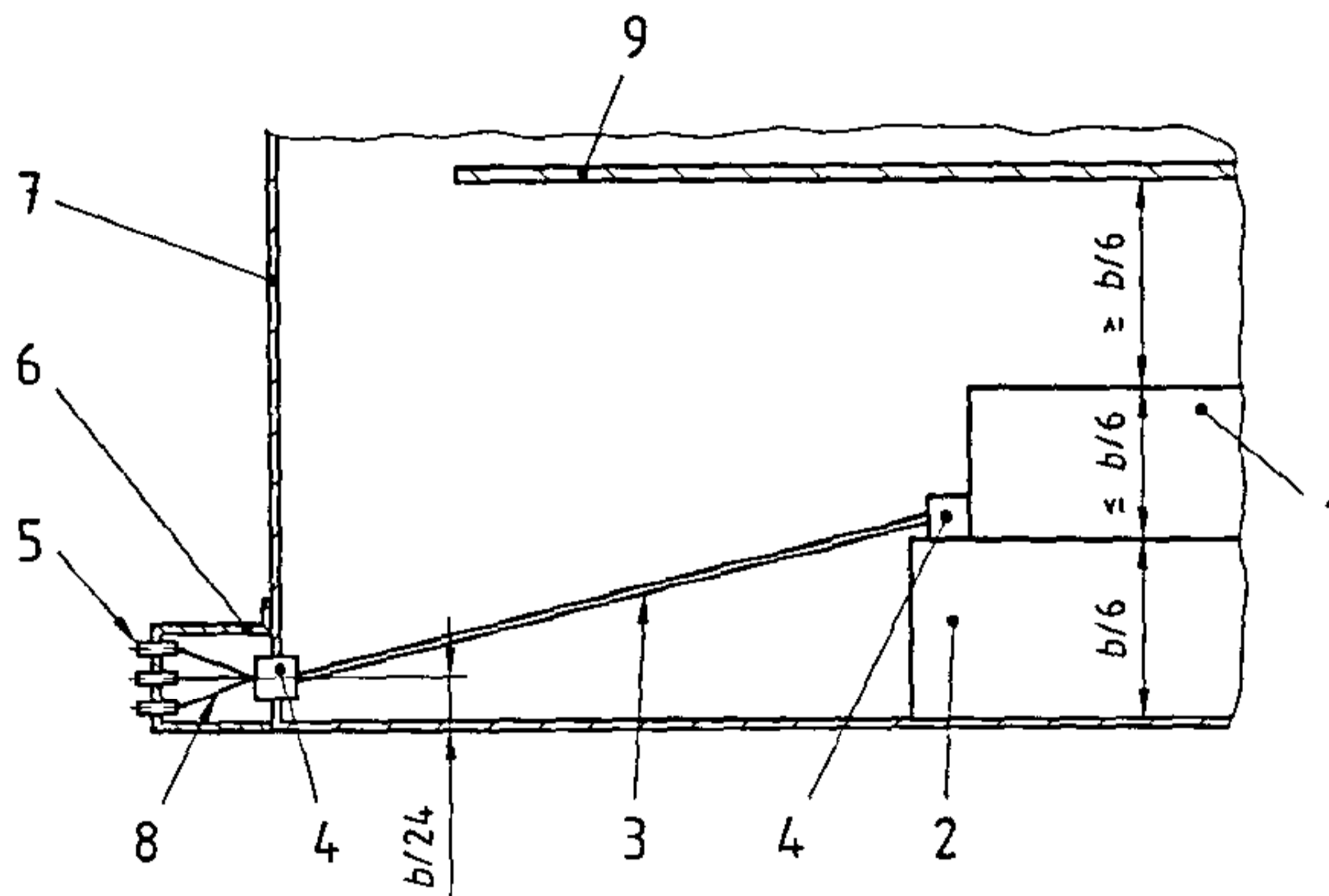
5.3.1 General

In order to maintain the homogeneous field in the TEM cell and obtain reproducible measurement results, the device under test shall be no larger than one-sixth of the cell (inside) height, b (see Figure 3 and Figure A.1). The device under test should be placed in the centre of the cell on a dielectric equipment support.

The device under test and the wiring harness may be positioned in either of two arrangements, depending on whether the exposure of the device under test and the wiring harness (5.3.2) or that of the device alone (5.3.3) is being tested.

5.3.2 Exposure of device under test and wiring harness (for major field coupling to the harness)

The height of the dielectric support is one sixth of cell height b (see Figure 3). In order to obtain reproducible measurement results, the device under test together with its wiring harness or printed circuit board shall be placed in the same position in the TEM cell for each measurement. In addition to the direct RF-field coupling to the device under test, the use of an unshielded harness or printed circuit board will result in a common mode electrical field coupling and a differential mode magnetic field coupling, depending on the inclination and the width of the harness or circuit board.

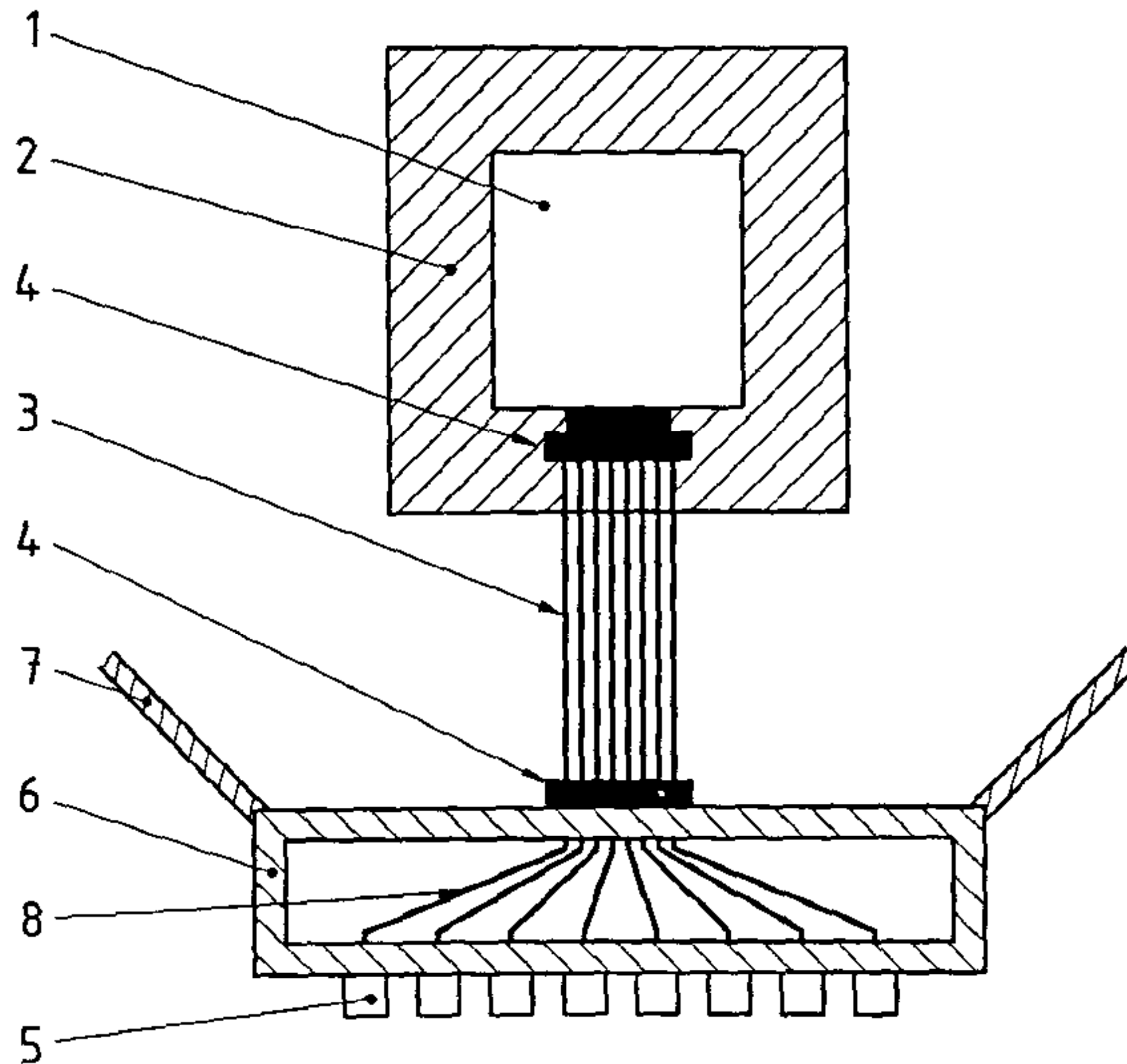


Key

- 1 Device under test
- 2 Dielectric support (relative permittivity $\epsilon_r \leq 1,4$)
- 3 Printed circuit board (no ground plane) or wiring harness, unshielded
- 4 Connector
- 5 Coaxial connectors
- 6 Connector panel
- 7 TEM cell wall
- 8 Cables
- 9 Septum
- b TEM cell height (see annex A)

Figure 3 — Example test set-up — Major field coupling to wiring harness (side view)

The connector panel should be attached to the TEM cell as close as possible to the printed lead system. The supply and signal leads from the connector in the cell wall are directly connected to the device under test using either a printed circuit board of length suitable for positioning the device under test in the allowed working region of the TEM cell, or a set of leads secured to a rigid support (see Figure 3 and Figure 4). The printed circuit board or supported wiring harness between the connector and the device under test will yield reproducible measurement results if the position of the leads and the device under test in the TEM cell are fixed.



Key

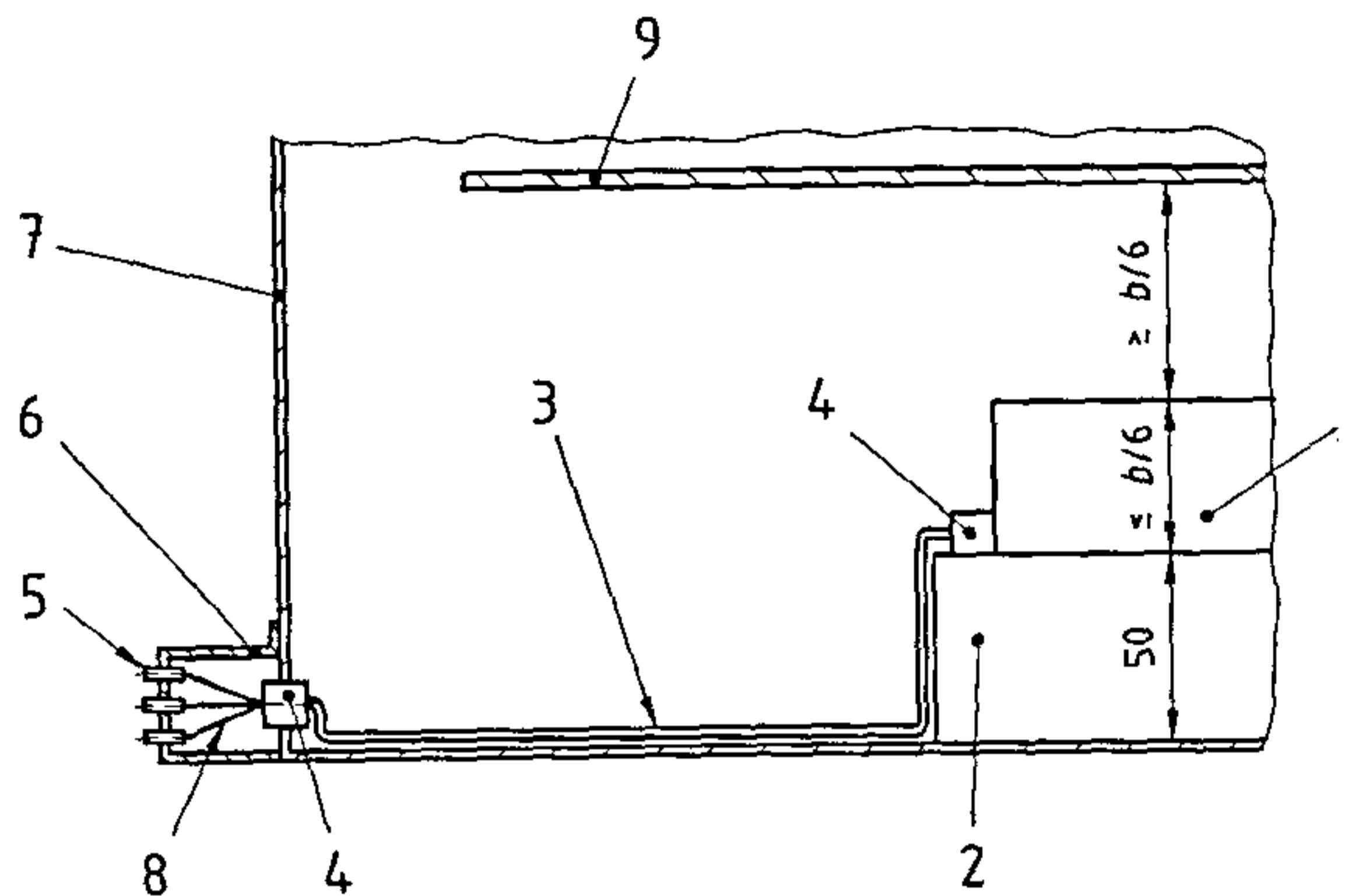
- 1 Device under test
- 2 Dielectric support (relative permittivity $\epsilon_r \leq 1,4$)
- 3 Printed circuit board or wiring harness
- 4 Connector
- 5 Coaxial connectors
- 6 Connector panel
- 7 TEM cell wall
- 8 Cables

NOTE RF filters can be connected to the coaxial connectors in the connector panel or directly to the connector in the TEM cell wall.

Figure 4 — Example test set-up — Major field coupling to wiring harness (top view)

5.3.3 Exposure of device under test alone (for major field coupling to that device)

The height of the dielectric support is 50 mm (see Figure 5). In order to obtain reproducible measurement results, the device under test shall be placed in the same position in the TEM cell for each measurement.



Key

- 1 Device under test
- 2 Dielectric support (relative permittivity $\epsilon_r \leq 1,4$)
- 3 Shielded wiring harness
- 4 Connector
- 5 Coaxial connectors
- 6 Connector panel
- 7 TEM cell wall
- 8 Cables
- 9 Septum
- b TEM cell height (see annex A)

Figure 5 — Example test set-up — Major field coupling to device under test (side view)

The connector panel should be attached to the TEM cell. The arrangement and nature of supply and signal leads shall be chosen in order to minimize the coupling on these leads, which shall be secured on the floor of the TEM cell and shielded between the connector in the cell wall and the device under test. This can be done by using metal tape with conductive adhesive to cover the leads on the floor of the TEM cell.

The shield shall be in electrical contact with the cell floor, but shall not be in contact with the case of the device under test.

6 Test procedure

6.1 Test plan

Prior to performing the test, a test plan shall be generated which shall cover the following:

- test set-up;
- frequency range;
- modulation;
- test set-up to be used (5.3.2 or 5.3.3);

- device under test mode of operation;
- device under test acceptance criteria;
- definition of test severity levels;
- test signal quality;
- use of net or output power measurements;
- device under test monitoring conditions;
- device under test orientation;
- test report content (see 6.3);
- any special instructions and changes from the standard test.

Each device under test shall be tested under the most significant situations: i.e. at least in stand-by mode and in a mode where all the actuators can be excited.

6.2 Test method

CAUTION — Hazardous voltages and fields may exist within the test area. Take care to ensure that the requirements for limiting the exposure of humans to RF energy are met.

Make a net, or output, power (see Figure 2) measurement and calculate the electric field using equation 1:

$$|E| = \frac{\sqrt{Z \times P}}{d} \quad (1)$$

where

- $|E|$ is the absolute value of the electric field in volts per metre;
- Z is the characteristic impedance of the TEM cell in ohms (typically 50 Ω);
- P is net power ($P = P_{\text{forward}} - P_{\text{reflected}}$) or output power, P_{output} , in watts;
- d is the distance, in metres, between the floor and the TEM cell septum ($b/2$ in Figure A.1).

An electrically small field-measuring device may be used to verify the calculated calibration curve for the field in the uniform field region.

The conductor on the printed circuit board shall be designed to handle the load current.

The doors of the TEM cell shall be closed at all times during the measurement.

Unused connectors shall be shielded, so that they do not emit radiation.

Wherever possible, use the actual vehicle loads, sensors and actuators.

Do not ground the device under test to the TEM cell floor unless it is intended that the actual vehicle configuration be simulated.

Care should be taken not to create ground loops.

6.3 Test report

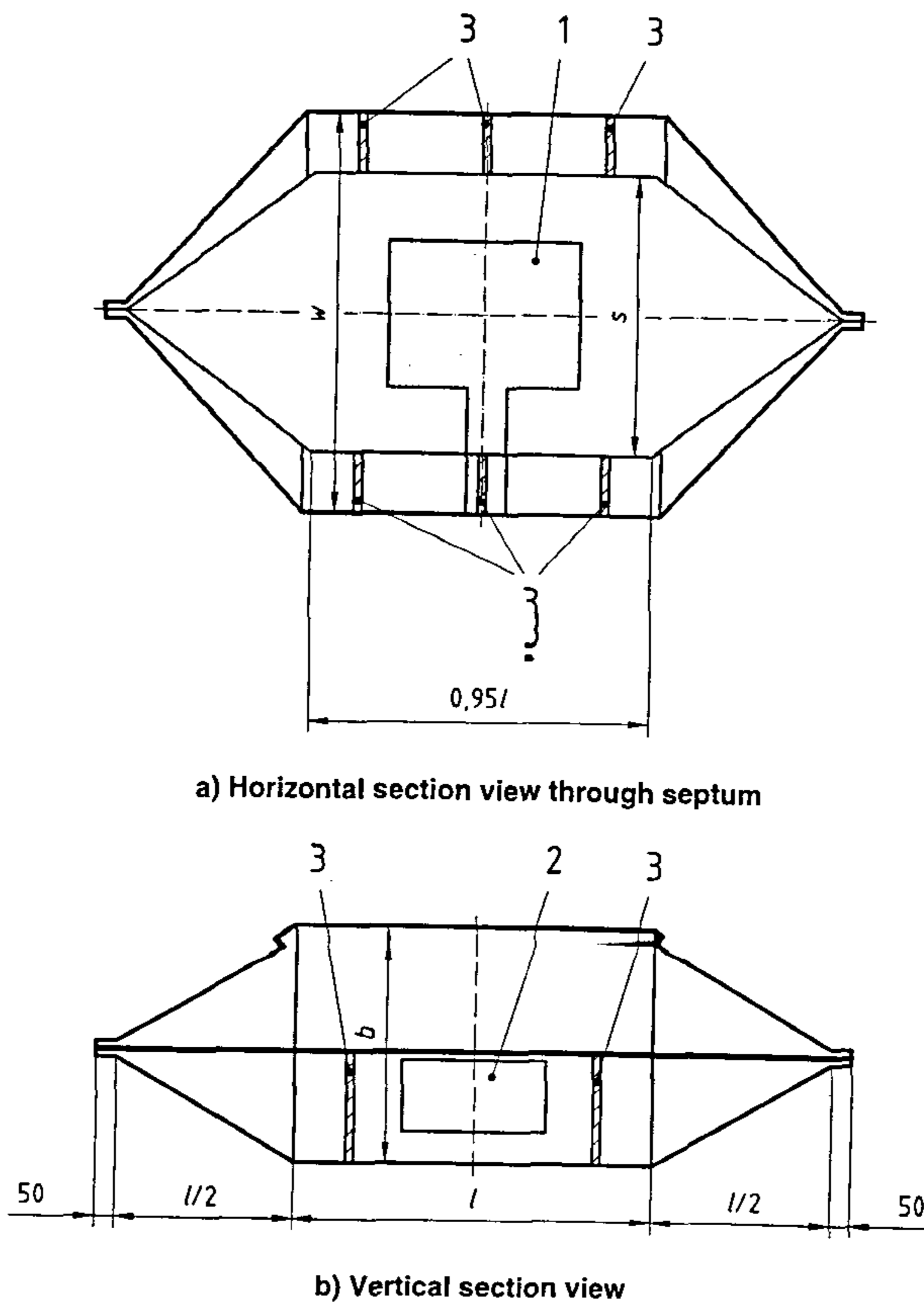
As required by the test plan, a test report shall be submitted detailing information on the test equipment, systems tested, frequencies, power levels, system interactions and other relevant information regarding the test.

Annex A (informative)

TEM cell dimensions

The dimensions of a typical TEM cell are shown in Figure A.1 and given in Table A.1.

Dimensions in millimetres



Key

- 1 Allowed working region: $0,33w$; $0,60l$
- 2 Access door
- 3 Dielectric supports

Figure A.1 — TEM cell

Table A.1 — Typical TEM cell dimensions

Upper frequency MHz	Cell form factor		TEM cell height	Septum width
	w/b	l/w	b m	s m
100	1,00	1,00	1,20	1,00
Typical for automotive component testing:				
200	1,69	0,66	0,56	0,70
	1,00	1,00	0,60	0,50
300	1,67	1,00	0,30	0,36
500	1,50	1,00	0,20	0,23

Annex B (informative)

Calculations and measurements of TEM-cell frequency range

B.1 General

The useful frequency range for each TEM cell and its test set-up can be determined by one of two methods, using, for example, a network analyzer.

B.2 Method 1

Verify that, for the whole useful frequency range at both inputs (of the empty TEM cell), the following requirements are met:

$$r = \sqrt{\frac{P_{\text{reflected}}}{P_{\text{forward}}}} \leq 0,15 \text{ or voltage standing wave ratio (VSWR)} = \frac{1+r}{1-r} \leq 1,35 \quad (\text{B.1})$$

where

r is the reflection factor;

$P_{\text{reflected}}$ is the reflected power;

P_{forward} is the forward power.

B.2.1 Method 2

Before testing the operative device under test, determine the TEM cell's resonances with the installed test set-up and device under test (without electrical connection). In this case, the TEM cell transmission loss in the useful frequency range shall be:

$$a_{\text{loss}} = \left| 10 \times \log \left(\frac{P_{\text{reflected}}}{P_{\text{reflected}}} + \frac{P_{\text{output}}}{P_{\text{forward}}} \right) \right| \leq 1 \text{ dB} \quad (\text{B.2})$$

where

a_{loss} is the TEM cell transmission loss;

$P_{\text{reflected}}$ is the reflected power;

P_{forward} is the forward power;

P_{output} is the power at the TEM cell output.

Measurements and results at frequencies at which the requirements (equation B.1 or equation B.2) are not met shall be disregarded, but shall be noted in the test report.

NOTE 1 A TEM cell impedance that does not equal 50Ω resulting in an r not equal to zero leads to a variation of the field strength along the TEM cell longitudinal direction. Such variations can be measured over the whole useful frequency range in the empty TEM cell. The relative field strength nonuniformity ($\overline{\Delta E}$) in the longitudinal direction of the TEM cell can be calculated with the following equation:

$$\overline{\Delta E} = \frac{E_{\max} - E_{\min}}{E_0} \approx 2r$$

(typical: $\overline{\Delta E} = 0,3$ for $r = 0,15$)

where

E_0 is the uniform field strength (without any reflection);

E_{\max} is the maximum value of a non-uniform field strength;

E_{\min} is the minimum value of a non-uniform field strength.

NOTE 2 Measurements at the TEM cell resonance frequencies are not allowed, because there is no field uniformity and no TEM mode (e.g. transmission line coupling instead of radiated coupling).

Annex C (informative)

Installation of external components and low pass filter design

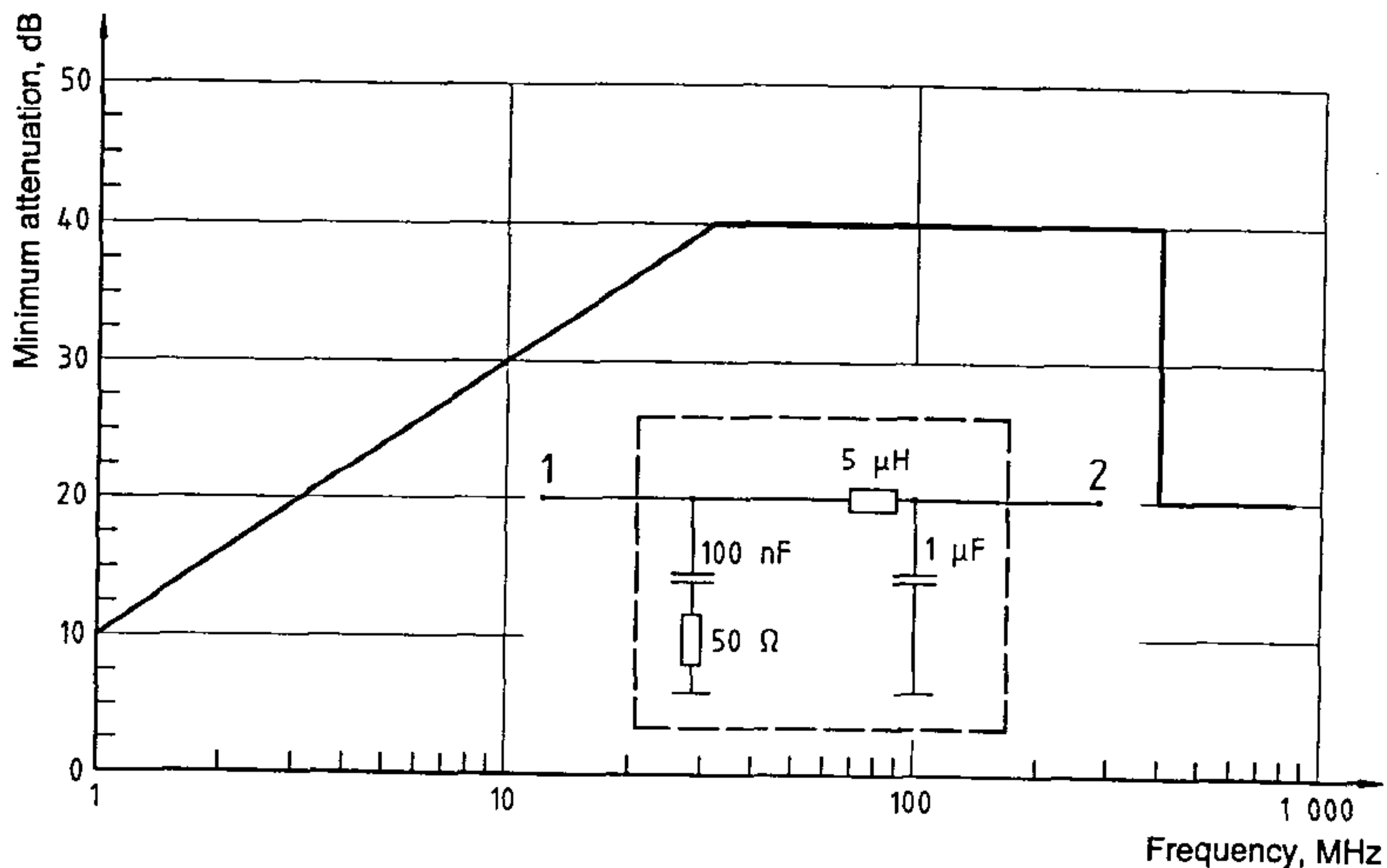
C.1 Connector panel

The wiring in the connector panel between connector (4) and the coaxial connectors (5) shown in Figure 3 should be done with 50 Ω coaxial cable to transfer the 50 Ω RF-impedance from the low pass filters attached to the coaxial connectors in the connector panel to the connector in the TEM cell wall.

C.2 External components and low pass filter

External components such as sensors, power supply and actuators should be connected to the filter at the connector panel.

All power and signal leads should be connected via a low pass filter (see Figure C.1) at the connector panel to the peripheral, to the directly connected parts at the panel or to the vehicle. This minimizes influences from the external connection, such as type and length of leads and lead impedances (peripheral if possible with original sensors and loads), and unwanted radio frequency (RF) emissions into, or out of, the TEM cell.



Key

- 1 Device under test (DUT) port
- 2 Supply port

Figure C.1 — Minimum attenuation and frequency response of the low pass filter with schematic circuit diagram (artificial network)

In Figure C.1, the low pass filter's minimum attenuation from 1 MHz to 800 MHz is shown. For leads with wanted RF signals in the TEM cell useful frequency range, the low pass filter must be designed in such a way that this minimum attenuation is only effective outside the RF bandwidth of the device under test.

The low pass filter should be designed so that its impedance (from the side of the device under test) does not change the electric data of the input and output of the device under test. Above the useful frequency range of the TEM cell, the impedance of the low pass filter shall be 50 Ω.

NOTE The transfer function is measured between the TEM cell input and the connector panel referenced to a 50 Ω impedance.

C.3 Design rules for the low pass filter

C.3.1 General

The minimum attenuation and frequency response of the low pass filter is as shown in Figure C.1. It is necessary to terminate the device under test at the TEM cell wall with a well-designed low pass RF filter in order to:

- limit the radio frequency emissions into the surrounding space;
- isolate the external peripheral or sensors from the TEM cell RF;
- define the RF load of the printed circuit board output with the result of minimized resonances;
- decouple the TEM cell septum and the circuit board from external loads;
- ensure that the RF filter does not influence the device under test and its external load in the useful frequency range.

All of the above can be measured and guaranteed via the transfer function between connector panel and TEM cell input.

EXAMPLE The transfer function is the same for connectors terminated by a short circuit and open circuit if the RF filter is used. If the transfer function is measured without using the RF filter, the results differ by up to 30 dB.

It is difficult to define a schematic circuit diagram for the low pass filter because its design is highly dependent on the positioning of the filter elements. It is therefore important to define the three ranges of filter responses versus frequency, as follows.

C.3.2 Lower cut-off frequency

It is not necessary to define the attenuation from DC to 1 MHz because TEM cell automotive immunity measurements normally start at 1 MHz.

C.3.3 Useful frequency range

The necessary attenuation, a_D , of the RF filter in the useful frequency range of the TEM cell can be calculated with the following equation:

$$a_D \geq 10 \times \log \frac{P_{RF,max}}{P_{E,max} \times a_{C,TEM} \times n_{max}} \approx 33 \text{ dB} \quad (C.1)$$

where

$P_{RF,max}$ is the maximum RF power outside the TEM cell, < 0,1 W;

$P_{E,max}$ is the TEM cell max. power input, 200 W;

$a_{C,TEM}$ is the coupling factor of the TEM cell, 0,01;

n_{max} is the number of connected leads, 100.

Since the coupling factor of the TEM cell decreases strongly for frequencies below 30 MHz, the minimum attenuation can be lowered, as shown in Figure C.1.

C.3.4 Upper cut-off frequency

Above the TEM cell cut-off frequency, only harmonics of the broadband amplifier with nominal 20 dB harmonic attenuation occur, so that a reduced filter attenuation of 20 dB is sufficient.

Since the impedance of the harness of the device under test outside the TEM cell lies between 20 Ω and 200 Ω , it is recommended that the high frequency impedance from the measurement side of the RF filter be 50 Ω . This compromise will allow the RF filter to be the same as the well known artificial network defined in CISPR 25 [1] (100 nF and 50 Ω).

Annex D (informative)

Function performance status classification (FPSC)

Suggested test severity levels and the frequency bands are given in Table D.1 and Table D.2, respectively.

NOTE See ISO 11452-1 for a detailed explanation of FPSC.

Table D.1 — Suggested test severity levels

Test severity level	Value V/m
I	50
II	100
III	150
IV	200
V	Specific value agreed between the users of this part of ISO 11452, if necessary.

Table D.2 — Frequency bands

Frequency band	Frequency range MHz
F1	$> 0,01$ to ≤ 10
F2	> 10 to ≤ 30
F3	> 30 to ≤ 80
F4	> 80 to ≤ 200

Bibliography

- [1] CISPR 25:1995, *Limits and methods of measurement of radio disturbance characteristics for the protection of receivers used on board vehicles.*

